Features

- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

PNP General Purpose Amplifier

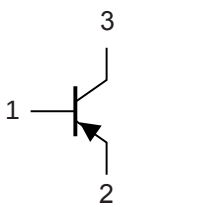
Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55℃ to +150℃
- Storage Temperature Range: -55℃ to +150℃
- Thermal Resistance: 556℃/W Junction to Ambient

Parameter		Symbol	Rating	Unit
Collector-Base Voltage	MMBTA55	V_{CBO}	-60	V
	MMBTA56		-80	
Collector-Emitter Voltage	MMBTA55	V_{CEO}	-60	V
	MMBTA56		-80	
Emitter-Base Voltage		V_{EBO}	-4	V
Continuous Collector Current		I_C	-500	mA
Power Dissipation		P_D	225	mW

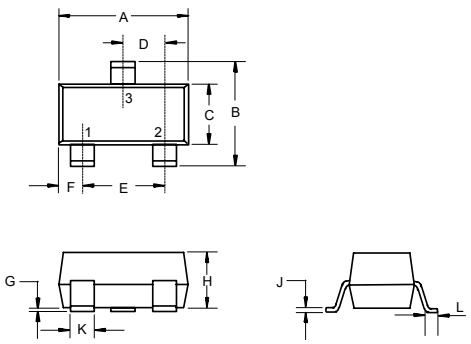
Marking:
MMBTA55: 2H
MMBTA56: 2GM

Internal Structure



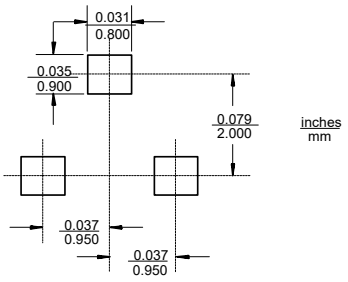
1.BASE
2.EMITTER
3.COLLECTOR

SOT-23



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.110	0.120	2.80	3.04	
B	0.083	0.104	2.10	2.64	
C	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
H	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



Electrical Characteristics @ T_A=25°C Unless Otherwise Specified

Parameter		Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	MMBTA55	$V_{(BR)CBO}$	-60			V	I_C=-100μA, I_E=0
	MMBTA56		-80			V	
Collector-Emitter Breakdown Voltage	MMBTA55	$V_{(BR)CEO}$	-60			V	I_C=-1mA, I_B=0
	MMBTA56		-80			V	
Emitter-Base Breakdown Voltage		$V_{(BR)EBO}$	-4			V	I_E=-100μA, I_C=0
Collector Cutoff Current	MMBTA55	I_{CBO}			-0.1	μA	V_{CB}=-60V, I_E=0
	MMBTA56				-0.1	μA	V_{CB}=-80V, I_E=0
Emitter Cutoff Current		I_{CES}			-0.1	μA	V_{CE}=-60V, I_B=0
DC Current Gain		$h_{FE(1)}$	100				V_{CE}=-1V, I_C=-10mA
		$h_{FE(2)}$	100				V_{CE}=-1V, I_C=-100mA
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$			-0.25	V	I_C=-100mA, I_B=-10mA
Base-Emitter Voltage		V_{BE}			-1.2	V	V_{CE}=-1V, I_C=-100mA
Transition Frequency		f_T	50			MHz	V_{CE}=-1V, I_C=-100mA, f=100MHz

Curve Characteristics

Fig. 1 - Static Characteristics

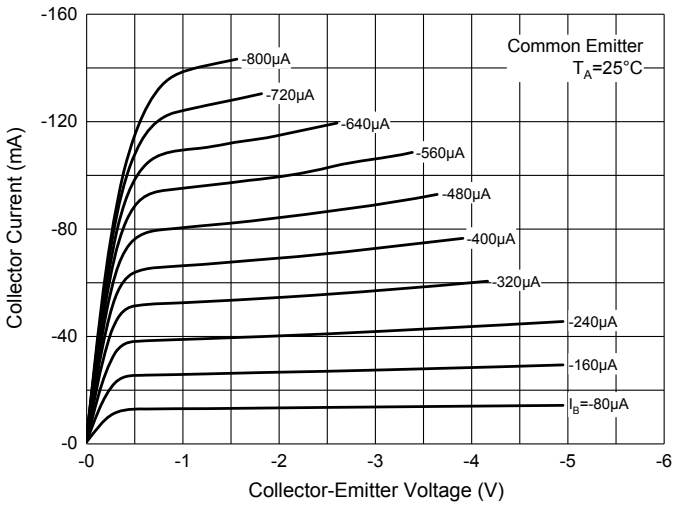


Fig. 2 - DC Current Gain Characteristics

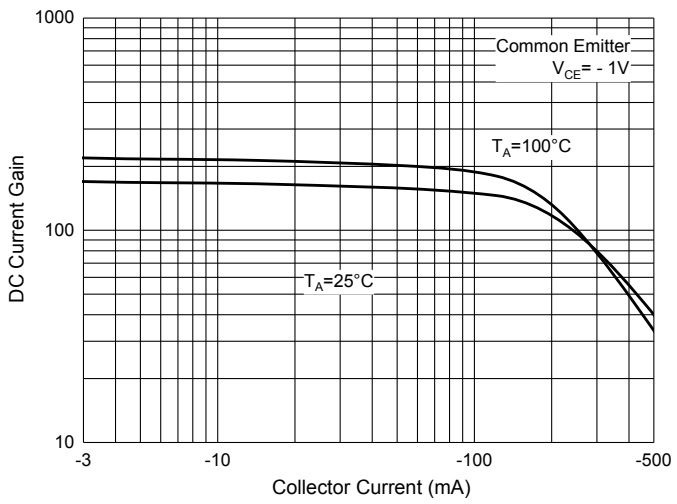


Fig. 3 - Collector-Emitter Saturation Voltage Characteristics

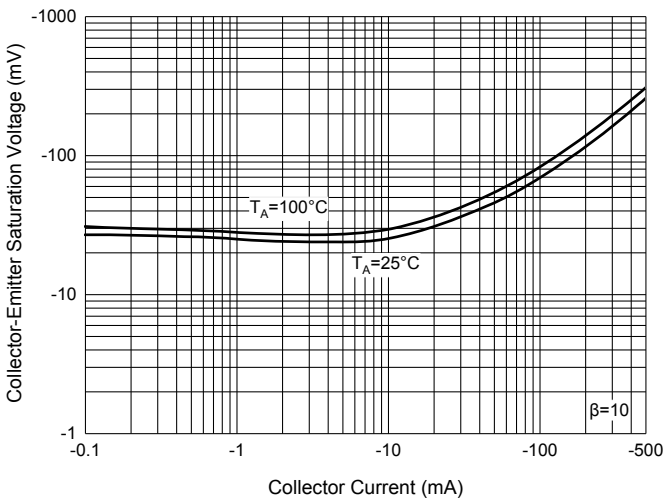


Fig. 4 - Base-Emitter Voltage Characteristics

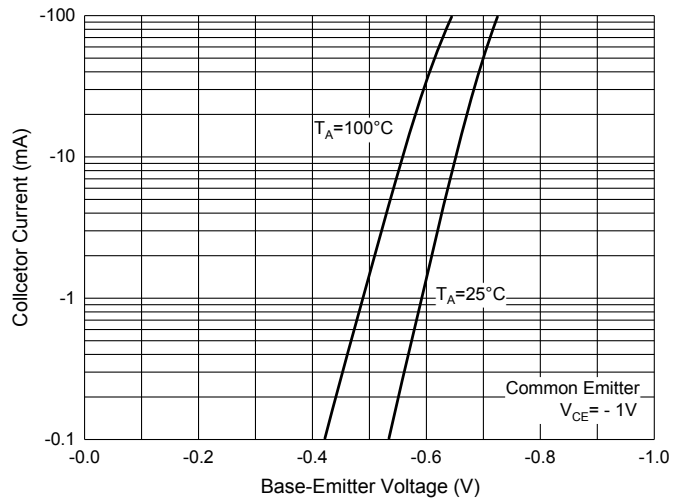
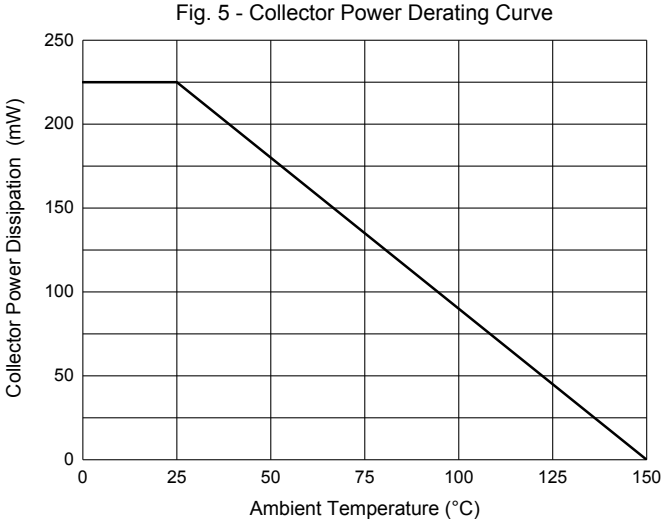


Fig. 5 - Collector Power Derating Curve



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

Note : Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF